NSN 5962-01-033-5504

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View Online at https://aerobasegroup.com/nsn/5962-01-033-5504

Body Length:

Between 0.747 inches and 0.815 inches

Body Width:

Between 0.220 inches and 0.280 inches

Body Height:

0.200 inches

Maximum Power Dissipation Rating:

525.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+200.0 degrees celsius

End Application:

Building @block 57 fscm 30003

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and high speed and wire-or outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

60.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Precious Material And Location:

Terminals gold

Test Data Document:

06424-10560 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

